



Features

- Small Body Outline Dimensions:
- Protects one I/O or power line
- Working Voltage: 12V
- Low Leakage Current

IEC COMPATIBILITY (EN61000-4)

- IEC 61000-4-2 (ESD) $\pm 30\text{kV}$ (air), $\pm 30\text{kV}$ (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 4A (8/20 μs)

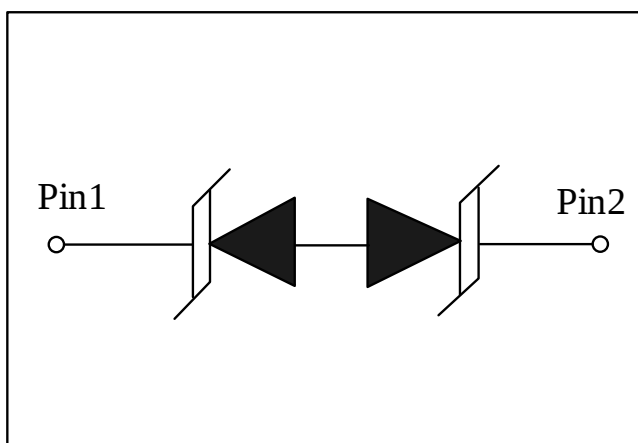
Mechanical Characteristics

- DFN0603-2L package
- Marking : Marking Code
- Packaging : Tape and Reel per EIA 481
- RoHS Compliant
- MSL1

Applications

- Cellular Handsets & Accessories
- Personal Digital Assistants (PDAs)
- Notebooks & Handhelds
- Portable Instrumentation
- Digital Cameras
- MP3 Players

Schematic & PIN Configuration

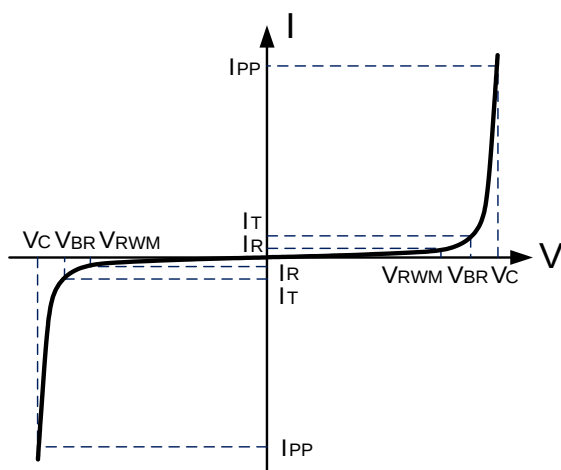


Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{PP}	80	Watts
Peak Pulse Current ($t_p = 8/20\mu s$)	I_{PP}	4	A
Operating Temperature	T_J	-55 to + 125	°C
Storage Temperature	T_{STG}	-55 to +150	°C

Electrical Parameters (T=25°C)

Symbol	Parameter
I_{PP}	Reverse Stand-Off Voltage
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Reverse Stand-Off Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current



Electrical Characteristics

E12DMSB						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V_{RWM}				12	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	13.3			V
Reverse Leakage Current	I_R	$V_{RWM}=12V$, $T=25^{\circ}C$			500	nA
Clamping Voltage	V_C	$I_{PP}=4A$, $t_p=8/20\mu s$		16.5	20	V
Dynamic Resistance ^{1,2}	R_{DYN}	TLP=0.2/100ns		0.36		Ω
ESD Clamping Voltage ¹	V_C	$I_{PP} = 4A$, $t_p = 0.2/100ns$ (TLP)		13.7		V
ESD Clamping Voltage ¹	V_C	$I_{PP} = 16A$, $t_p = 0.2/100ns$ (TLP)		18		V
Junction Capacitance	C_j	$V_R = 0V$, $f = 1MHz$		7	12	pF

Notes : 1、TLP Setting : $t_p=100ns$, $t_r=0.2ns$, I_{TLP} and V_{TLP} sample window: $t_1=70ns$ to $t_2=90ns$.

2、Dynamic resistance calculated from $I_{PP}=4A$ to $I_{PP}=16A$ using “Best Fit”.

Typical Characteristics

Figure 1: Peak Pulse Power Vs Pulse Time

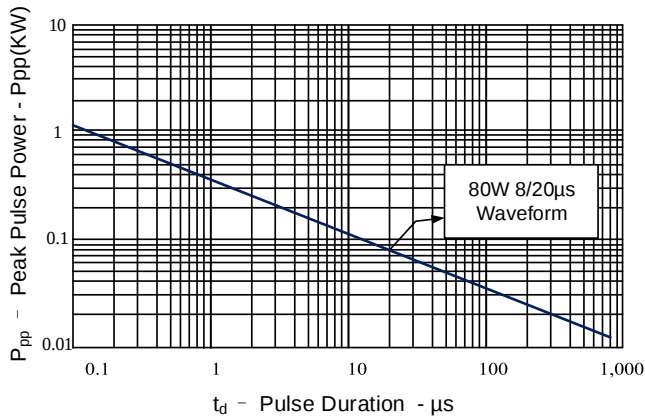


Figure 2: Power Derating Curve

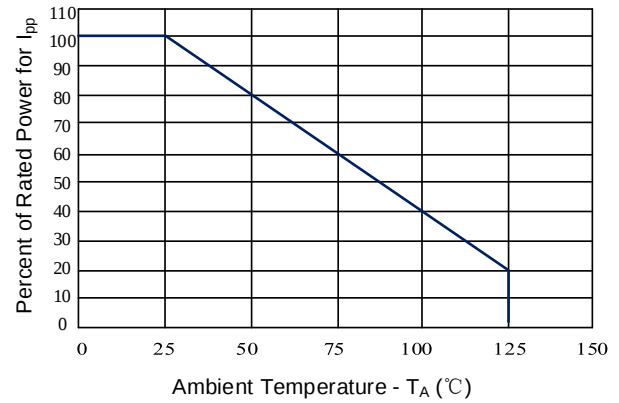


Figure 3: Clamping Voltage vs. Peak Pulse Current

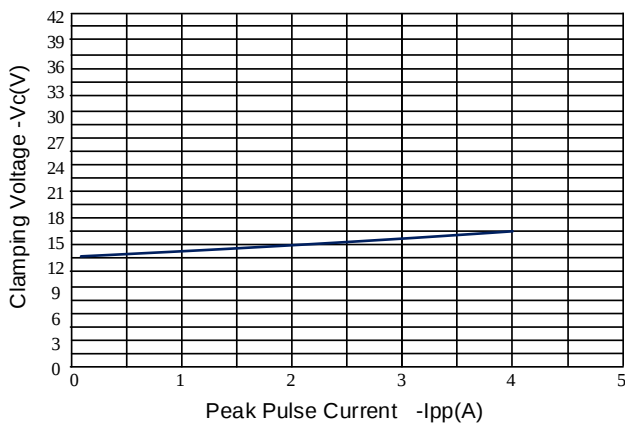


Figure 4: Normalized Junction Capacitance vs. Reverse Voltage

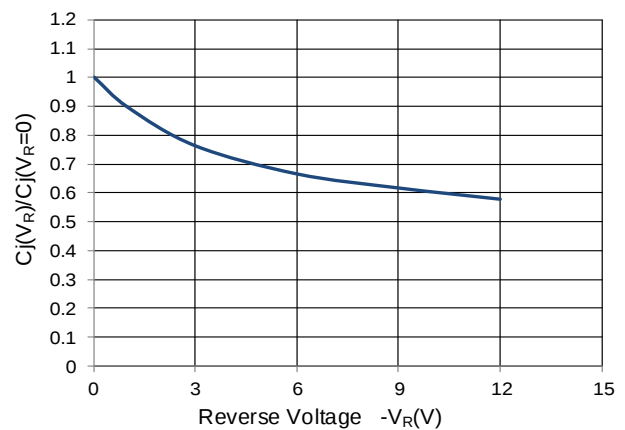


Figure 5: TLP Positive I-V Curve

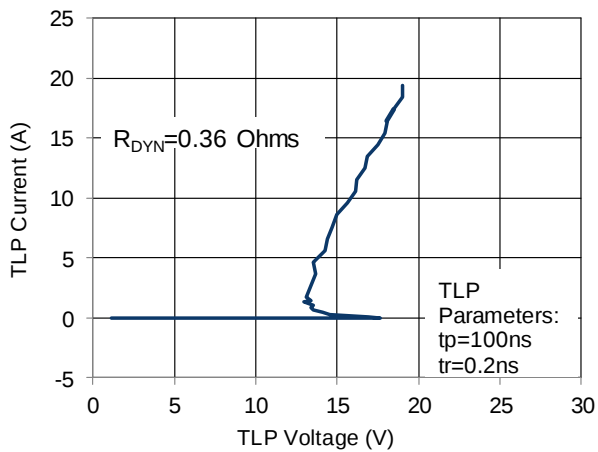
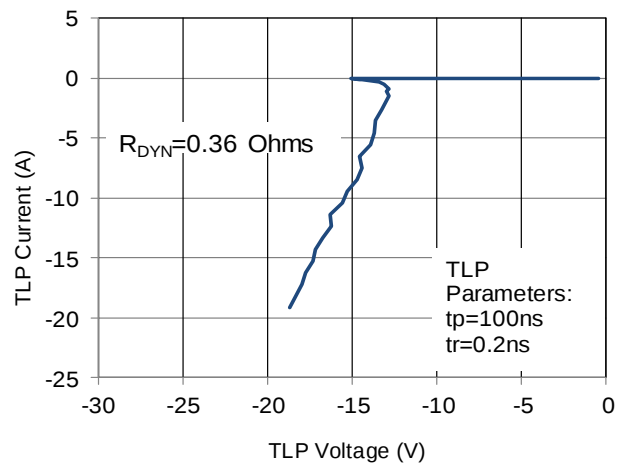
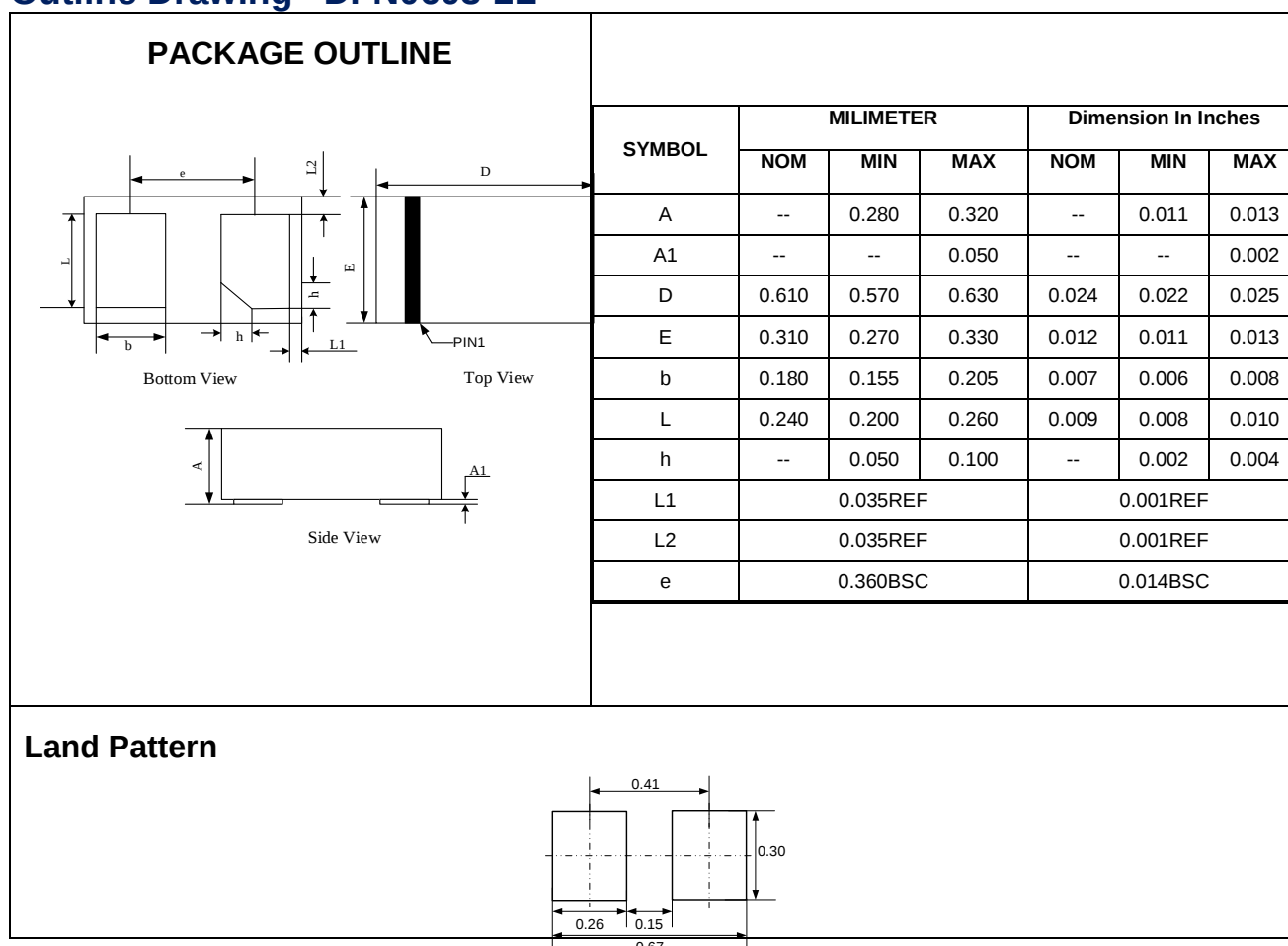


Figure 6: TLP Negative I-V Curve



Outline Drawing –DFN0603-2L



Marking Codes

Part Number	Marking Code
E12DMSB	1 F Σ 2

Package Information

Qty: 15k/Reel

Revision History

No.	Version	Date	Revision Item	Request	Function and characteristic checking	Package dimension checking	Typos checking
1	1.0	2019-10-18	Released Version	Qi Shu Kun	Qi Shu Kun	Liu Jia Ying	Liu Jia Ying
2	1.1	2020-03-17	Add MSL level	Qi Shu Kun	Qi Shu Kun	Liu Jia Ying	Liu Jia Ying